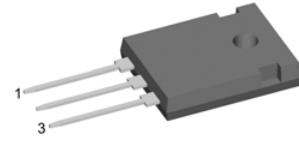
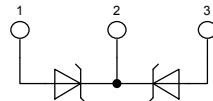


**Schottky Diode Gen 2**

High Performance Schottky Diode  
Low Loss and Soft Recovery  
Common Cathode

**Part number****DSB 60 C 45 HB**

Backside: cathode

**Features / Advantages:**

- Very low V<sub>f</sub>
- Extremely low switching losses
- low I<sub>rm</sub> values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

**Applications:**

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

**Package:**

- Housing: TO-247
- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

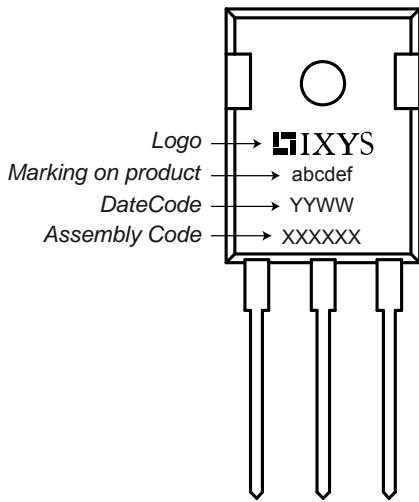
Symbol	Definition	Conditions		Ratings		
		min.	typ.	max.	Unit	
V <sub>RRM</sub>	max. repetitive reverse voltage			45	V	
I <sub>R</sub>	reverse current	V <sub>R</sub> = 45V	T <sub>VJ</sub> = 25°C	10	mA	
		V <sub>R</sub> = 45V	T <sub>VJ</sub> = 100°C	100	mA	
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 30A	T <sub>VJ</sub> = 25°C	0.62	V	
		I <sub>F</sub> = 60A		0.88	V	
		I <sub>F</sub> = 30A	T <sub>VJ</sub> = 125°C	0.58	V	
		I <sub>F</sub> = 60A		0.86	V	
I <sub>FAV</sub>	average forward current	rectangular d = 0.5	T <sub>C</sub> = 125°C	30	A	
V <sub>F0</sub> r <sub>F</sub>	threshold voltage slope resistance } for power loss calculation only		T <sub>VJ</sub> = 150°C	0.31	V	
				8.7	mΩ	
R <sub>thJC</sub>	thermal resistance junction to case			0.95	K/W	
T <sub>VJ</sub>	virtual junction temperature		-55	150	°C	
P <sub>tot</sub>	total power dissipation		T <sub>C</sub> = 25°C	130	W	
I <sub>FSM</sub>	max. forward surge current	t = 10 ms (50 Hz), sine	T <sub>VJ</sub> = 45°C	320	A	
C <sub>J</sub>	junction capacitance	V <sub>R</sub> = 5V; f = 1 MHz	T <sub>VJ</sub> = 25°C	980	pF	

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$I_{RMS}$	RMS current	per pin <sup>1)</sup>			50	A
$R_{thCH}$	thermal resistance case to heatsink			0.25		K/W
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				6		g
$M_D$	mounting torque		0.8		1.2	Nm
$F_c$	mounting force with clip		20		120	N

<sup>1)</sup>  $I_{RMS}$  is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

### Product Marking



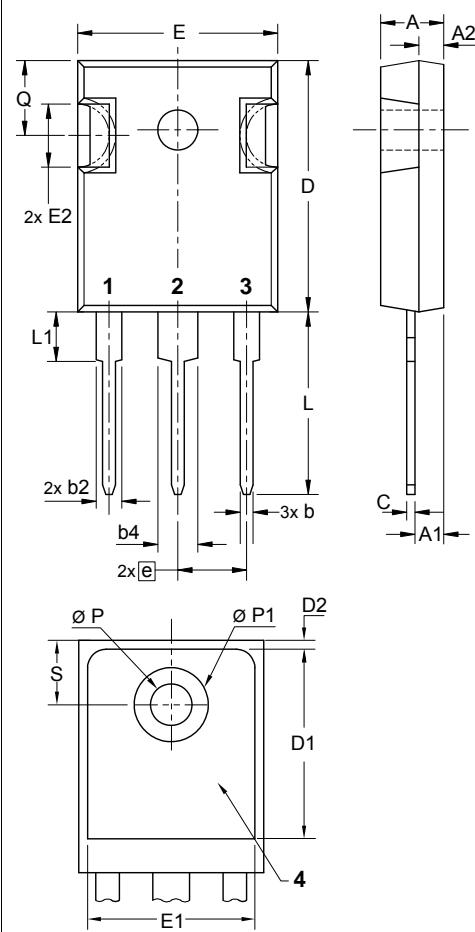
### Part number

D = Diode  
 S = Schottky Diode  
 B = ultra low VF  
 60 = Current Rating [A]  
 C = Common Cathode  
 45 = Reverse Voltage [V]  
 HB = TO-247AD (3)

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSB 60 C 45 HB	DSB60C45HB	Tube	30	505549

Similar Part	Package	Voltage class
DSB60C45PB	TO-220AB (3)	45

## Outlines TO-247



Sym.	Inches min. max.	Millimeter min. max.
A	0.185 0.209	4.70 5.30
A1	0.087 0.102	2.21 2.59
A2	0.059 0.098	1.50 2.49
D	0.819 0.845	20.79 21.45
E	0.610 0.640	15.48 16.24
E2	0.170 0.216	4.31 5.48
e	0.215 BSC	5.46 BSC
L	0.780 0.800	19.80 20.30
L1	- 0.177	- 4.49
Ø P	0.140 0.144	3.55 3.65
Q	0.212 0.244	5.38 6.19
S	0.242 BSC	6.14 BSC
b	0.039 0.055	0.99 1.40
b2	0.065 0.094	1.65 2.39
b4	0.102 0.135	2.59 3.43
c	0.015 0.035	0.38 0.89
D1	0.515 -	13.07 -
D2	0.020 0.053	0.51 1.35
E1	0.530 -	13.45 -
Ø P1	- 0.29	- 7.39